

# MOS FIELD EFFECT TRANSISTOR $\mu$ PA1872B

## N-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

### DESCRIPTION

The  $\mu$  PA1872B is a switching device, which can be driven directly by a 2.5 V power source.

The  $\mu$  PA1872B features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

### FEATURES

- 2.5 V drive available
- Low on-state resistance  
 $R_{DS(on)1} = 13.0 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.5 \text{ V, } I_D = 5.0 \text{ A)}$   
 $R_{DS(on)2} = 13.5 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.0 \text{ V, } I_D = 5.0 \text{ A)}$   
 $R_{DS(on)3} = 15.5 \text{ m}\Omega \text{ MAX. (} V_{GS} = 3.1 \text{ V, } I_D = 5.0 \text{ A)}$   
 $R_{DS(on)4} = 18.0 \text{ m}\Omega \text{ MAX. (} V_{GS} = 2.5 \text{ V, } I_D = 5.0 \text{ A)}$
- Built-in G-S protection diode against ESD

### ORDERING INFORMATION

PART NUMBER	PACKAGE
$\mu$ PA1872BGR-9JG	Power TSSOP8

### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ )

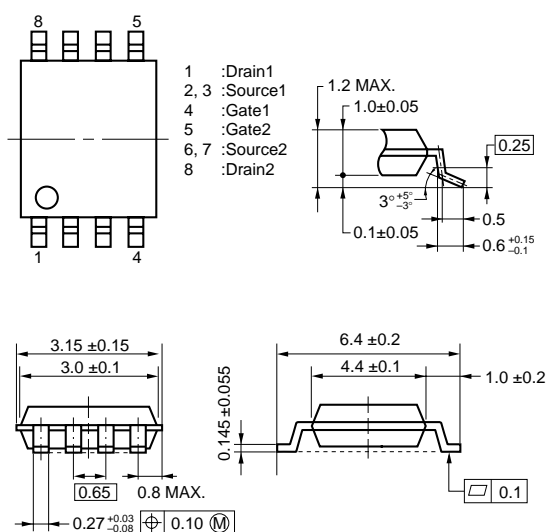
Drain to Source Voltage ( $V_{GS} = 0 \text{ V}$ )	$V_{DSS}$	20.0	V
Gate to Source Voltage ( $V_{DS} = 0 \text{ V}$ )	$V_{GSS}$	$\pm 12.0$	V
Drain Current (DC) <sup>Note 1</sup>	$I_{D(DC)}$	$\pm 10.0$	A
Drain Current (pulse) <sup>Note 2</sup>	$I_{D(pulse)}$	$\pm 80.0$	A
Total Power Dissipation <sup>Note 1</sup>	$P_T$	2.0	W
Channel Temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

**Notes 1.** Mounted on ceramic board of  $50 \text{ cm}^2 \times 1.1 \text{ mm}$

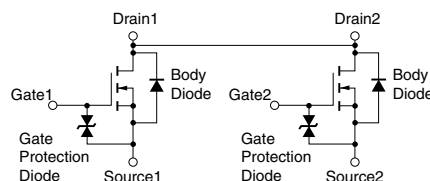
**2.**  $PW \leq 10 \text{ }\mu\text{s}$ , Duty Cycle  $\leq 1\%$

**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

### PACKAGE DRAWING (Unit: mm)



### EQUIVALENT CIRCUIT



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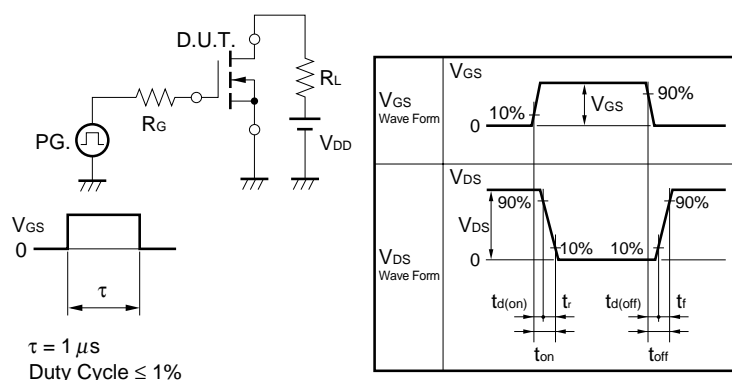
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# ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)

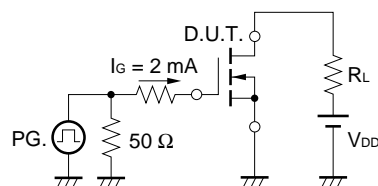
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 20.0 V, V <sub>GS</sub> = 0 V			1.0	μA
Gate Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±12.0 V, V <sub>DS</sub> = 0 V			±10.0	μA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10.0 V, I <sub>D</sub> = 1.0 mA	0.50	1.00	1.50	V
Forward Transfer Admittance <b>Note</b>	y <sub>fs</sub>	V <sub>DS</sub> = 10.0 V, I <sub>D</sub> = 5.0 A	5			S
Drain to Source On-state Resistance <b>Note</b>	R <sub>DS(on)1</sub>	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 5.0 A	8.0	10.0	13.0	mΩ
	R <sub>DS(on)2</sub>	V <sub>GS</sub> = 4.0 V, I <sub>D</sub> = 5.0 A	8.5	10.5	13.5	mΩ
	R <sub>DS(on)3</sub>	V <sub>GS</sub> = 3.1 V, I <sub>D</sub> = 5.0 A	9.0	11.0	15.5	mΩ
	R <sub>DS(on)4</sub>	V <sub>GS</sub> = 2.5 V, I <sub>D</sub> = 5.0 A	10.0	13.0	18.0	mΩ
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 10.0 V		945		pF
Output Capacitance	C <sub>oss</sub>	V <sub>GS</sub> = 0 V		220		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1.0 MHz		160		pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 10.0 V, I <sub>D</sub> = 5.0 A		47		ns
Rise Time	t <sub>r</sub>	V <sub>GS</sub> = 4.0 V		315		ns
Turn-off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> = 10 Ω		255		ns
Fall Time	t <sub>f</sub>			330		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DD</sub> = 16.0 V		10.0		nC
Gate to Source Charge	Q <sub>GS</sub>	V <sub>GS</sub> = 4.0 V		2.5		nC
Gate to Drain Charge	Q <sub>GD</sub>	I <sub>D</sub> = 10.0 A		4.5		nC
Body Diode Forward Voltage <b>Note</b>	V <sub>F(S-D)</sub>	I <sub>F</sub> = 10.0 A, V <sub>GS</sub> = 0 V		0.83		V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 10.0 A, V <sub>GS</sub> = 0 V		240		ns
Reverse Recovery Charge	Q <sub>rr</sub>	di/dt = 50 A/μs		220		nC

**Note** Pulsed: PW ≤ 350 μs, Duty Cycle ≤ 2%

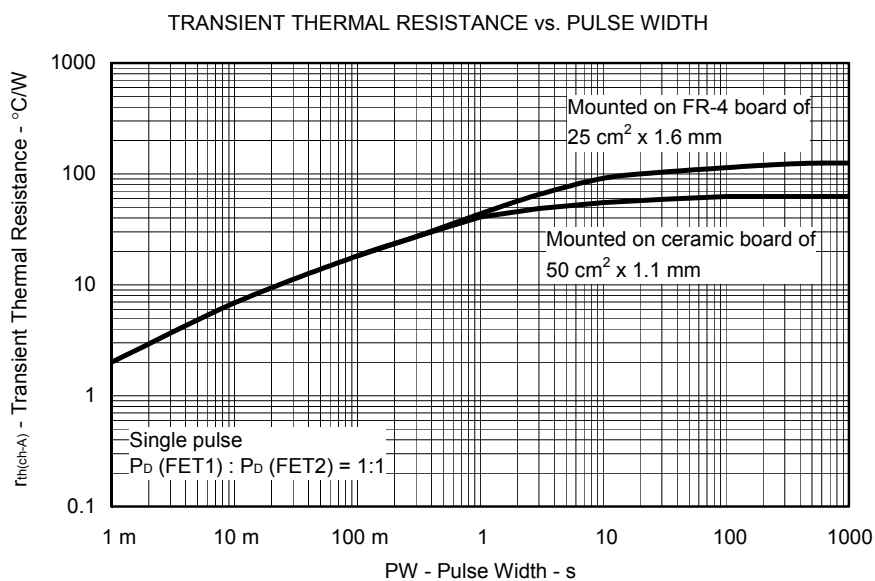
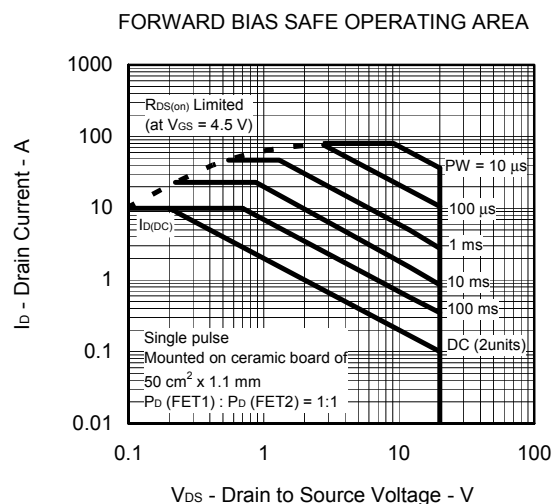
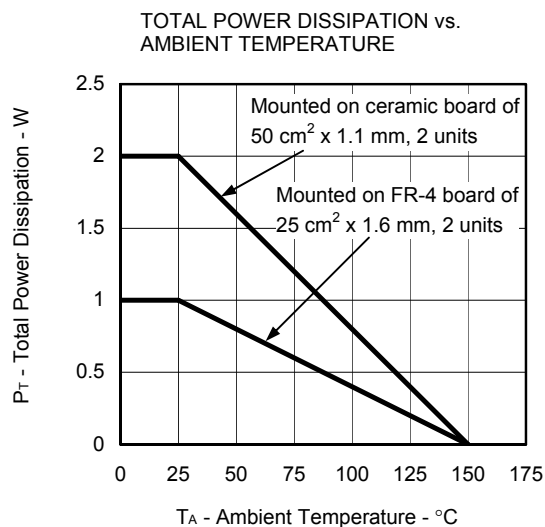
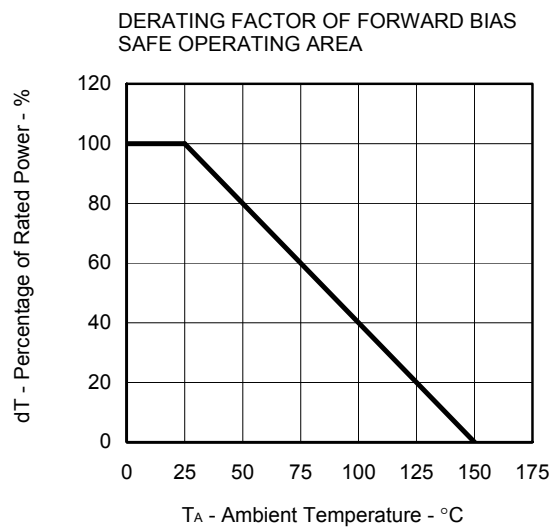
## TEST CIRCUIT 1 SWITCHING TIME



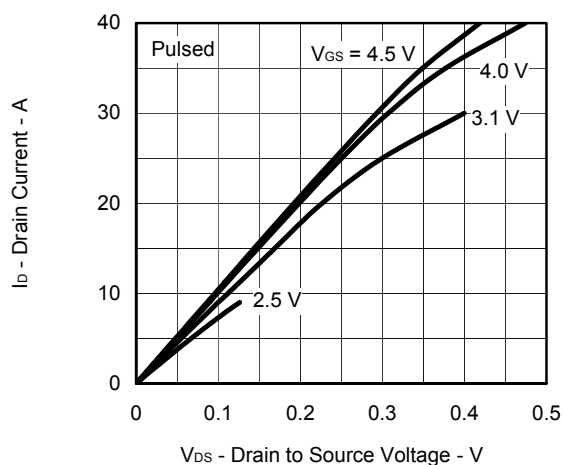
## TEST CIRCUIT 2 GATE CHARGE



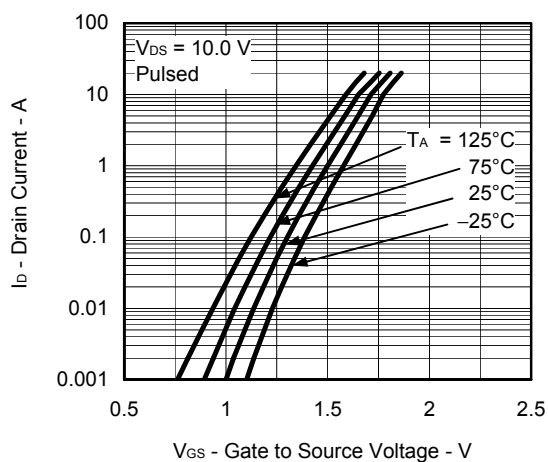
TYPICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ )



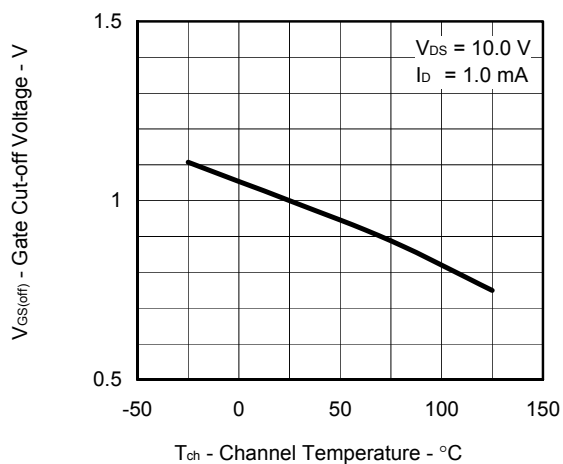
DRAIN CURRENT vs.  
DRAIN TO SOURCE VOLTAGE



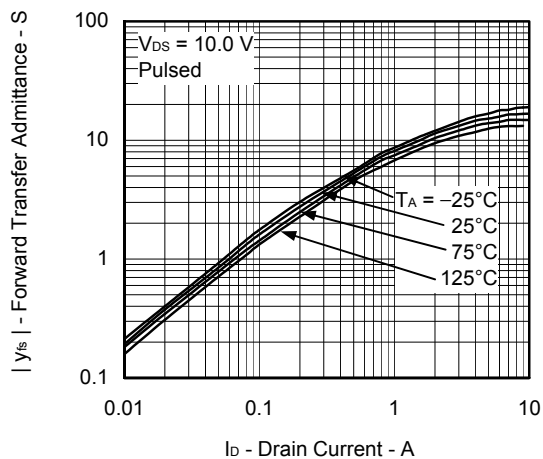
FORWARD TRANSFER CHARACTERISTICS



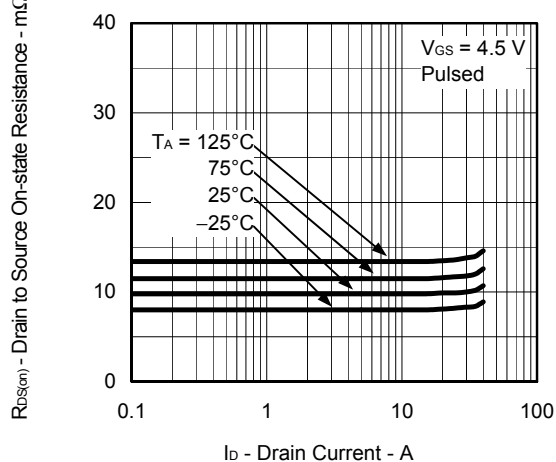
GATE CUT-OFF VOLTAGE vs.  
CHANNEL TEMPERATURE



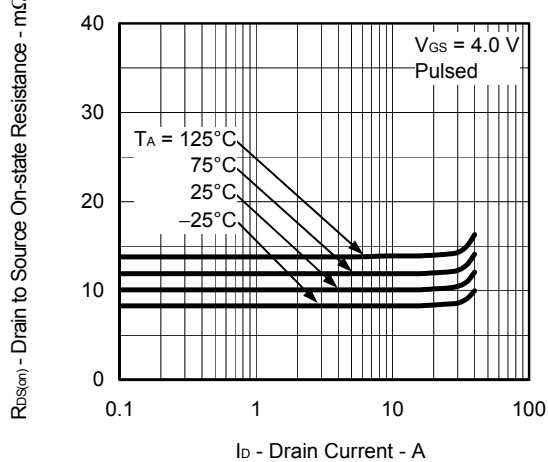
FORWARD TRANSFER ADMITTANCE vs.  
DRAIN CURRENT

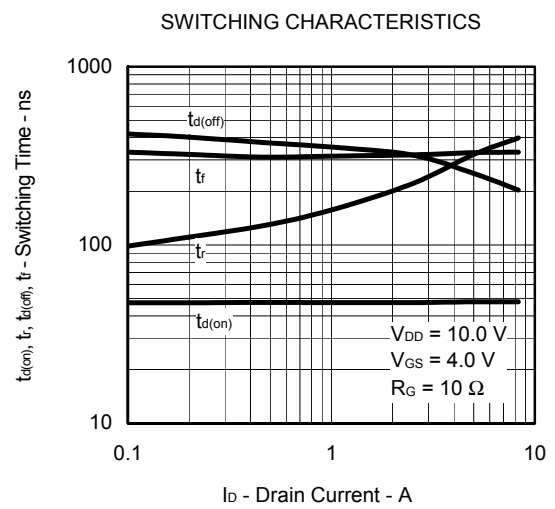
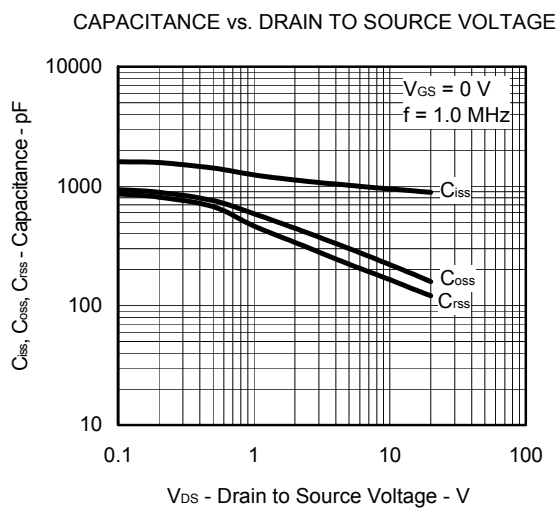
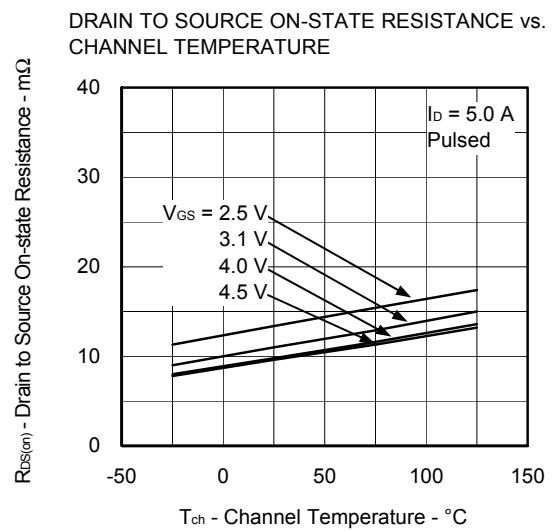
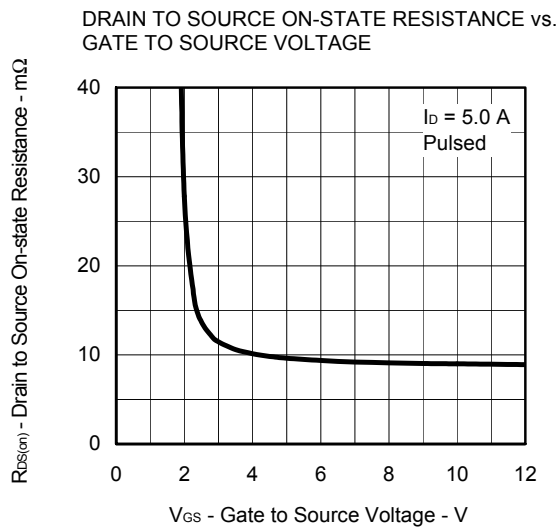
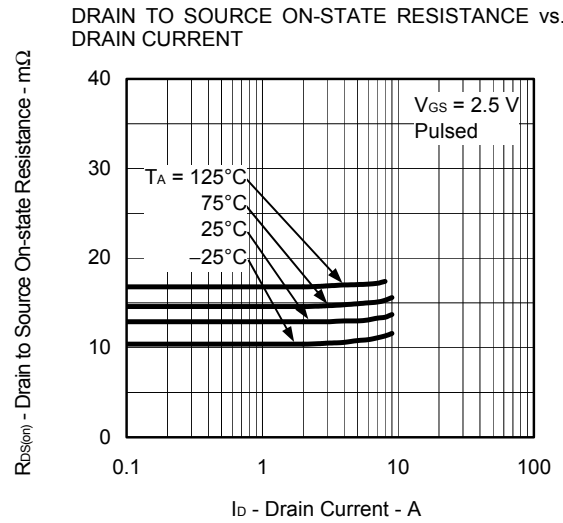
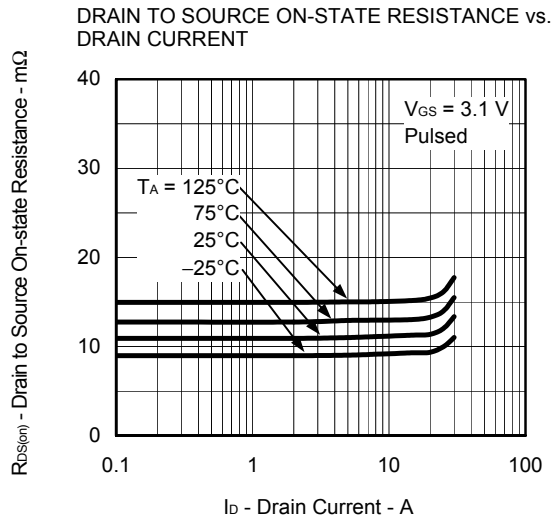


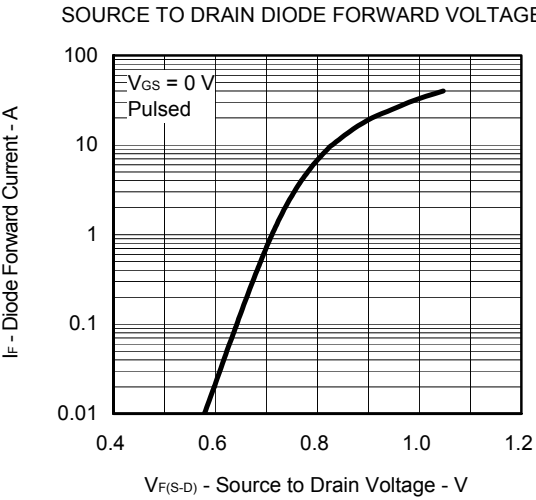
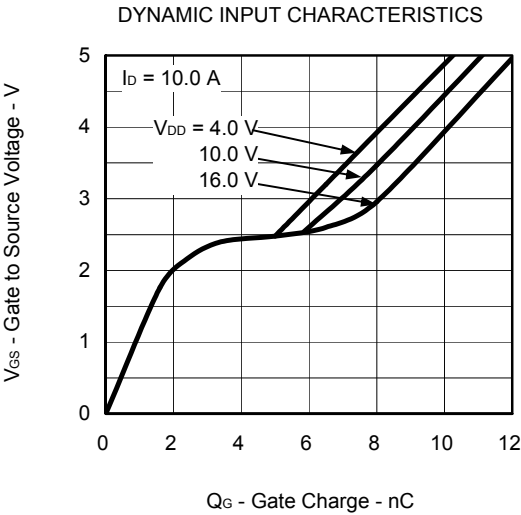
DRAIN TO SOURCE ON-STATE RESISTANCE vs.  
DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs.  
DRAIN CURRENT







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